

## 3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O

## IDT74LVC16245A

## FEATURES:

- Typical tSK(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- VCC = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Supports hot insertion
- · Available in SSOP and TSSOP packages

## DRIVE FEATURES:

- High Output Drivers: ±24mA
- · Reduced system switching noise

### **APPLICATIONS:**

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

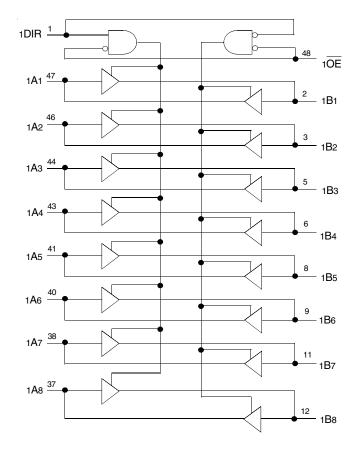
## FUNCTIONAL BLOCK DIAGRAM

## DESCRIPTION:

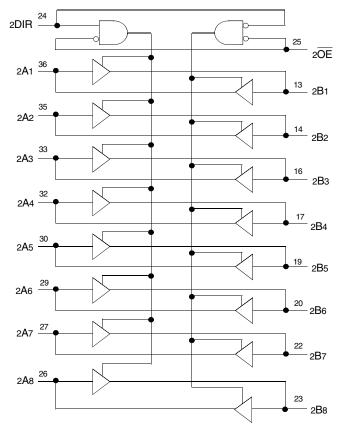
This 16-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate this device as either two independent 8-bit transceivers or one 16-bit transceiver. The direction control pin (DIR) controls the direction of data flow. The output enable pin  $(\overline{OE})$  overrides the direction control and disables both ports. All inputs are designed with hysteresis for improved noise margin.

All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

The LVC16245A has been designed with a  $\pm$ 24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.



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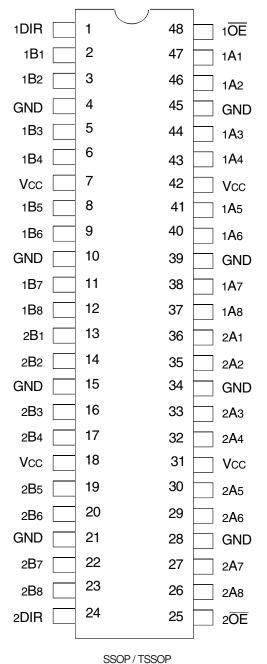


## IDT74LVC16245A

#### 3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

#### **INDUSTRIAL TEMPERATURE RANGE**

## **PIN CONFIGURATION**



TOP VIEW

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	–50 to +50	mA
Ік Іок	Continuous Clamp Current, Vi < 0 or Vo < 0	-50	mA
ICC ISS	Continuous Current through each Vcc or GND	±100	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

### CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	pF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

## PIN DESCRIPTION

Pin Names Description	
xŌĒ	Output Enable Inputs (Active LOW)
xDIR	Direction Control Input
xAx	Side A Inputs or 3-State Outputs
xBx	Side B Inputs or 3-State Outputs

## FUNCTION TABLE (EACH 8-BIT SECTION)<sup>(1)</sup>

Inp	outs	
×ŌĒ	xDIR	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	Z

NOTES:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

Z = High-Impedance

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40 °C to +85 °C

Symbol	Parameter	Tes	t Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V			_	0.7	V
		Vcc = 2.7V to 3.6V		_	—	0.8	
lih lil	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V	-	_	±5	μA
Iozh Iozl	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = 0 to 5.5V	-	-	±10	μA
loff	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo $\leq$ 5.	5V		_	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	-	—	10	μA
lccz			$3.6 \le VIN \le 5.5V^{(2)}$	_	—	10	
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other inputs at Vcc or GND		_	_	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

## OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Іон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = - 6mA	2	_	
		Vcc = 2.3V	Іон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V	-	2.4	_	
		Vcc = 3V	Iон = - 24mA	2.2	—	
Vol	OutputLOWVoltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IoL = 6mA	—	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IoL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

# OPERATING CHARACTERISTICS, Vcc = $3.3V \pm 0.3V$ , TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
Cpd	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	38	pF
Cpd	Power Dissipation Capacitance per Transceiver Outputs disabled		4	

## SWITCHING CHARACTERISTICS<sup>(1)</sup>

		Vcc = 2.7V		$VCC = 3.3V \pm 0.3V$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	—	4.7	1	4	ns
<b>t</b> PHL	xAx to xBx, xBx to xAx					
tРZH	Output Enable Time	_	6.7	1.5	5.5	ns
tPZL	xOE to xAx or xBx					
tPHZ	Output Disable Time	_	7.1	1.5	6.6	ns
tPLZ	xOE to xAx or xBx					
tsk(o)	Output Skew <sup>(2)</sup>	—	—	—	1	ns

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA =  $-40^{\circ}$ C to + 85°C.

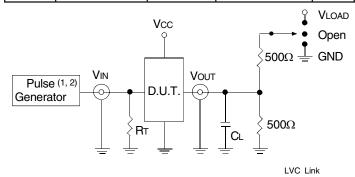
2. Skew between any two outputs of the same package and switching in the same direction.

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#### **INDUSTRIAL TEMPERATURE RANGE**

# **TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS**

Symbol	Vcc <sup>(1)</sup> =3.3V±0.3V	Vcc <sup>(1)</sup> =2.7V	Vcc <sup>(2)</sup> =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vт	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
Vнz	300	300	150	mV
CL	50	50	30	рF





#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

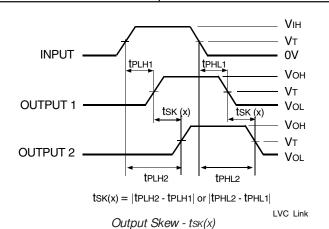
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz: tF  $\leq$  2.5ns: tR  $\leq$  2.5ns. 2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

### SWITCH POSITION

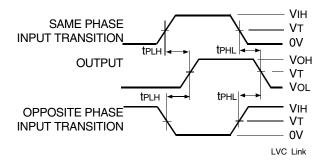
Test	Switch		
Open Drain Disable Low Enable Low	Vload		
Disable High Enable High	GND		
All Other Tests	Open		



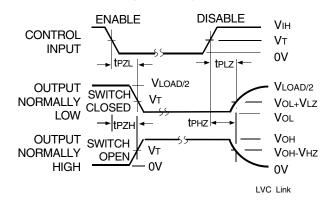


For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.

- 1. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank. 2



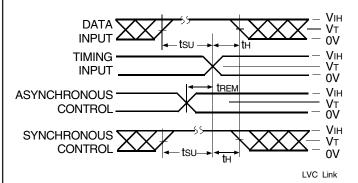
Propagation Delay

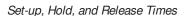


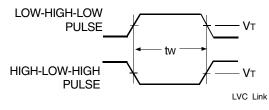
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

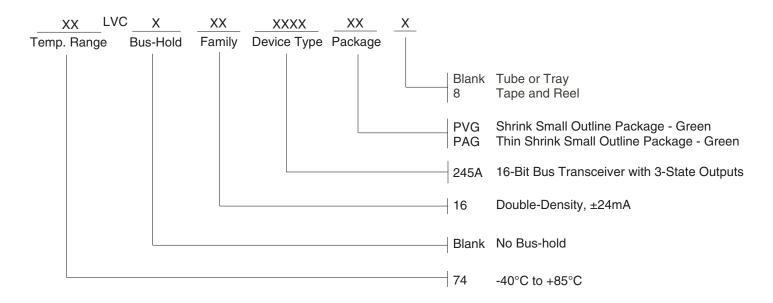






Pulse Width

## ORDERINGINFORMATION



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TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

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